NSR15TW1

Triple RF Schottky Diode

These diodes are designed for analog and digital applications, including DC based signal detection and mixing applications.

Features:

- Low Capacitance (<1 pF)
- Low V_F (390 mV typical @ 1 mA)
- Low $V_{F\Delta}$ (1 mV typical @ 1 mA)

Benefits:

- Reduced Parasitic Losses
- Accurate Signal Measurement

MAXIMUM RATINGS

| Rating | Symbol | Max | Unit |
|--|-----------------------------------|----------------|------|
| Peak Reverse Voltage | V _R | 15 | V |
| Forward Current | ١ _F | 30 | mA |
| Operating and Storage Temperature Range | T _J , T _{stg} | –65 to +150 | °C |
| ESD Rating: Class 1 per Human Body Mode Class A per Machine Model | 1 | | |

THERMAL CHARACTERISTICS

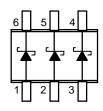
| Characteristic | Symbol | Value | Unit |
|---|----------------|-------|------|
| Maximum Thermal Resistance – Junction to Ambient | R_{\thetaJA} | 500 | °C/W |



ON Semiconductor[™]

http://onsemi.com

RF SCHOTTKY BARRIER DIODES 15 VOLTS, 30 mA





SC-88 CASE 419B STYLE 15

MARKING DIAGRAM



OZ = Specific Device Code M = Date Code

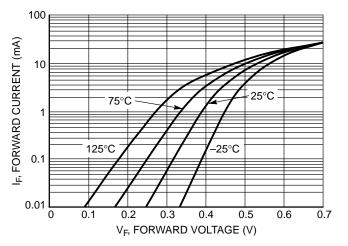
ORDERING INFORMATION

| Device | Package | Shipping | |
|------------|---------|------------------|--|
| NSR15TW1T2 | SC-88 | 3000/Tape & Reel | |

NSR15TW1

ELECTRICAL CHARACTERISTICS

| Characteristic | Symbol | Min | Тур | Max | Unit |
|--|-----------------|-----|-----|-----|------|
| Breakdown Voltage (I _R = 10 μA) | V _{BR} | 15 | 20 | - | V |
| Reverse Leakage (V _R = 1 V) | I _R | - | 2 | 50 | nA |
| Forward Voltage (I _F = 1 mA) | V _{F1} | - | 390 | 415 | mV |
| Forward Voltage (I _F = 10 mA) | V _{F2} | - | 530 | 680 | mV |
| Delta V _F (I _F = 1 mA, All Diodes) | ΔV_F | - | 1 | 15 | mV |
| Capacitance (V _F = 0 V, f = 1 MHz) | CT | - | 0.8 | 1 | pF |





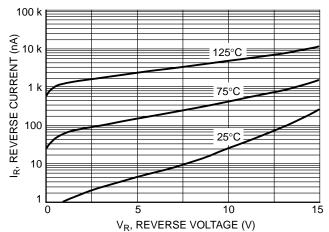


Figure 2. Reverse Current versus Reverse Voltage

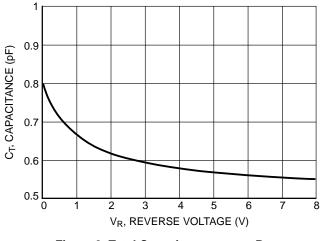


Figure 3. Total Capacitance versus Reverse Voltage

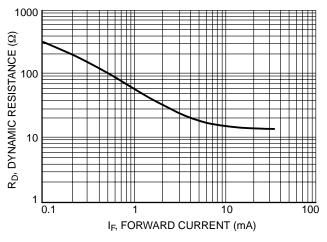


Figure 4. Dynamic Resistance versus Forward Current

NSR15TW1

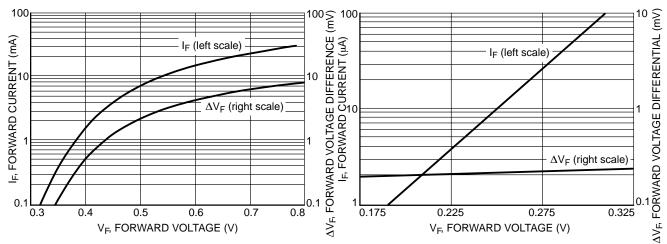
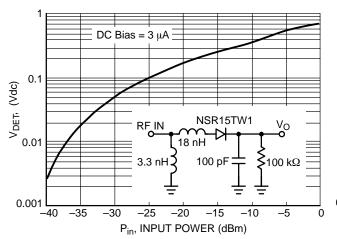


Figure 5. Typical V_F Match at Mixer Bias Levels

Figure 6. Typical V_F Match at Detector Bias Levels



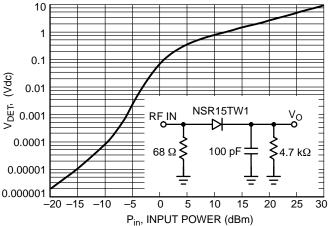




Figure 8. Typical Output Voltage versus Input Power, Large Signal Detector Operating at 915 MHz

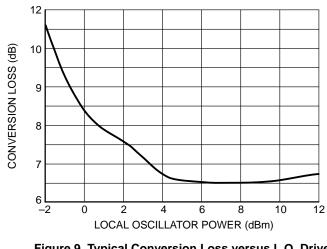


Figure 9. Typical Conversion Loss versus L.O. Drive, 2.0 GHz

0.043

0.004





- XXX = Specific Device Code

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering

details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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SC-88/SC70-6/SOT-363 CASE 419B-02 ISSUE Y

DATE 11 DEC 2012

| STYLE 1: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2 | STYLE 2: CANCELLED | STYLE 3: CANCELLED | STYLE 4: PIN 1. CATHODE 2. CATHODE 3. COLLECTOR 4. EMITTER 5. BASE 6. ANODE | STYLE 5: PIN 1. ANODE 2. ANODE 3. COLLECTOR 4. EMITTER 5. BASE 6. CATHODE | STYLE 6: PIN 1. ANODE 2 2. N/C 3. CATHODE 1 4. ANODE 1 5. N/C 6. CATHODE 2 |
|--|-----------------------|--|---|---|---|
| STYLE 7: PIN 1. SOURCE 2 2. DRAIN 2 3. GATE 1 4. SOURCE 1 5. DRAIN 1 6. GATE 2 | STYLE 8: CANCELLED | STYLE 9: PIN 1. EMITTER 2 2. EMITTER 1 3. COLLECTOR 1 4. BASE 1 5. BASE 2 6. COLLECTOR 2 | STYLE 10: PIN 1. SOURCE 2 2. SOURCE 1 3. GATE 1 4. DRAIN 1 5. DRAIN 2 6. GATE 2 | STYLE 11: PIN 1. CATHODE 2 2. CATHODE 2 3. ANODE 1 4. CATHODE 1 5. CATHODE 1 6. ANODE 2 | STYLE 12: PIN 1. ANODE 2 2. ANODE 2 3. CATHODE 1 4. ANODE 1 5. ANODE 1 6. CATHODE 2 |
| STYLE 13: | STYLE 14: | STYLE 15: | STYLE 16: | STYLE 17: | STYLE 18: |
| PIN 1. ANODE | PIN 1. VREF | PIN 1. ANODE 1 | PIN 1. BASE 1 | PIN 1. BASE 1 | PIN 1. VIN1 |
| 2. N/C | 2. GND | 2. ANODE 2 | 2. EMITTER 2 | 2. EMITTER 1 | 2. VCC |
| 3. COLLECTOR | 3. GND | 3. ANODE 3 | 3. COLLECTOR 2 | 3. COLLECTOR 2 | 3. VOUT2 |
| 4. EMITTER | 4. IOUT | 4. CATHODE 3 | 4. BASE 2 | 4. BASE 2 | 4. VIN2 |
| 5. BASE | 5. VEN | 5. CATHODE 2 | 5. EMITTER 1 | 5. EMITTER 2 | 5. GND |
| 6. CATHODE | 6. VCC | 6. CATHODE 1 | 6. COLLECTOR 1 | 6. COLLECTOR 1 | 6. VOUT1 |
| STYLE 19: | STYLE 20: | STYLE 21: | STYLE 22: | STYLE 23: | STYLE 24: |
| PIN 1. I OUT | PIN 1. COLLECTOR | PIN 1. ANODE 1 | PIN 1. D1 (i) | PIN 1. Vn | PIN 1. CATHODE |
| 2. GND | 2. COLLECTOR | 2. N/C | 2. GND | 2. CH1 | 2. ANODE |
| 3. GND | 3. BASE | 3. ANODE 2 | 3. D2 (i) | 3. Vp | 3. CATHODE |
| 4. V CC | 4. EMITTER | 4. CATHODE 2 | 4. D2 (c) | 4. N/C | 4. CATHODE |
| 5. V EN | 5. COLLECTOR | 5. N/C | 5. VBUS | 5. CH2 | 5. CATHODE |
| 6. V REF | 6. COLLECTOR | 6. CATHODE 1 | 6. D1 (c) | 6. N/C | 6. CATHODE |
| STYLE 25: | STYLE 26: | STYLE 27: | STYLE 28: | STYLE 29: | STYLE 30: |
| PIN 1. BASE 1 | PIN 1. SOURCE 1 | PIN 1. BASE 2 | PIN 1. DRAIN | PIN 1. ANODE | PIN 1. SOURCE 1 |
| 2. CATHODE | 2. GATE 1 | 2. BASE 1 | 2. DRAIN | 2. ANODE | 2. DRAIN 2 |
| 3. COLLECTOR 2 | 3. DRAIN 2 | 3. COLLECTOR 1 | 3. GATE | 3. COLLECTOR | 3. DRAIN 2 |
| 4. BASE 2 | 4. SOURCE 2 | 4. EMITTER 1 | 4. SOURCE | 4. EMITTER | 4. SOURCE 2 |
| 5. EMITTER | 5. GATE 2 | 5. EMITTER 2 | 5. DRAIN | 5. BASE/ANODE | 5. GATE 1 |
| 6. COLLECTOR 1 | 6. DRAIN 1 | 6. COLLECTOR 2 | 6. DRAIN | 6. CATHODE | 6. DRAIN 1 |

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

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